## NSN 5962-01-349-2199

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View Online at https://aerobasegroup.com/nsn/5962-01-349-2199

Overall Length:			
1.280 inches			
Overall Height:			
0.400 inches			
Body Length:			
1.280 inches			
Body Width:			
Between 0.220 inches and 0.310 inches			
Body Height:			
Between 0.140 inches and 0.185 inches			
Maximum Power Dissipation Rating:			
1.2 watts			
Operating Tempurature Range:			
-55.0/+125.0 degrees celsius			
Storage Tempurature Range:			
-65.0/+150.0 degrees celsius			
Features Provided:			
Hermetically sealed and burn in and monolithic and programmable			
Inclosure Material:			
Ceramic			
Inclosure Configuration:			
Dual-in-line			
Output Logic Form:			
Complementary-metal oxide-semiconductor logic			
Input Circuit Pattern:			
22 input			
Case Outline Source And Designator:			
D-9 mil-m-38510			
Current Rating Per Characteristic:			
100.00 milliamperes supply			
Terminal Surface Treatment:			
Solder			
Product Name:			
And-or-logic array			
Voltage Rating And Type Per Characteristic:			
-0.5 volts power source and 7.0 volts power source			
Capitance Rating Per Characteristic:			
5.00 input picofarads and 8.00 output picofarads			

**Memory Device Type:** Pal

**Time Rating Per Chacteristic:** 

40.00 nanoseconds propagation delay

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Test	Data	Docum	ent
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life: N/a

**Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

Fiig:

A458a0